

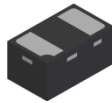
**Features**

- Fast Switching Speed: Maximum of 50ns
- High Reverse Breakdown Voltage: 325V
- Low Leakage Current: Maximum of 50nA when  $V_R = 5V$  or Maximum of 150nA when  $V_R = 250V$  at Room Temperature
- Ultra Small Plastic SMD Package: 1.0mm x 0.6mm x 0.5mm
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

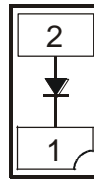
**Mechanical Data**

- Case: X1-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 <sup>(e4)</sup>
- Weight: 0.0009 grams (Approximate)

X1-DFN1006-2



Bottom View



Device Schematic

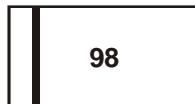
**Ordering Information** (Note 5)

Part Number	Qualification	Case	Packaging
BAS521LPQ-7B	Automotive	X1-DFN1006-2	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. Automotive products are AEC-Q10x qualified and are PPAP capable. Refer to <https://www.diodes.com/quality/>.
  5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**

BAS521LP-7B



Top View  
Bar Denotes  
Cathode Side

98 = Product Type Marking Code

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	325	V
Working Peak Reverse Voltage	V <sub>RWM</sub>	325	V
DC Blocking Voltage	V <sub>R</sub>	325	V
Forward Current (Note 6)	I <sub>F</sub>	400	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0μs	I <sub>FSM</sub>	8.0	A
Repetitive Peak Forward Current @ t=8.3ms	I <sub>FRM</sub>	3.0	A

**Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	400	mW
Thermal Resistance Junction to Ambient Air (Note 6)	R <sub>θJA</sub>	312	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	V <sub>(BR)R</sub>	300	—	V	I <sub>R</sub> = 100μA
Forward Voltage	V <sub>F</sub>	—	1.1	V	I <sub>F</sub> = 100mA
Reverse Current (Note 7)	I <sub>R</sub>	—	50	nA	V <sub>R</sub> = 5V
		—	150	nA	V <sub>R</sub> = 250V
		—	100	μA	V <sub>R</sub> = 250V, T <sub>J</sub> = +150°C
Total Capacitance	C <sub>T</sub>	—	5	pF	V <sub>R</sub> = 0, f = 1.0MHz
Reverse Recovery Time	t <sub>rr</sub>	—	50	ns	I <sub>F</sub> = I <sub>R</sub> = 30mA, I <sub>rr</sub> = 0.1 x I <sub>R</sub> , R <sub>L</sub> = 100Ω

Notes: 6. Part is mounted on a FR-7 substrate PC board, with 1" x 1" 2oz copper pad.  
7. Short duration pulse test used to minimize self-heating effect.

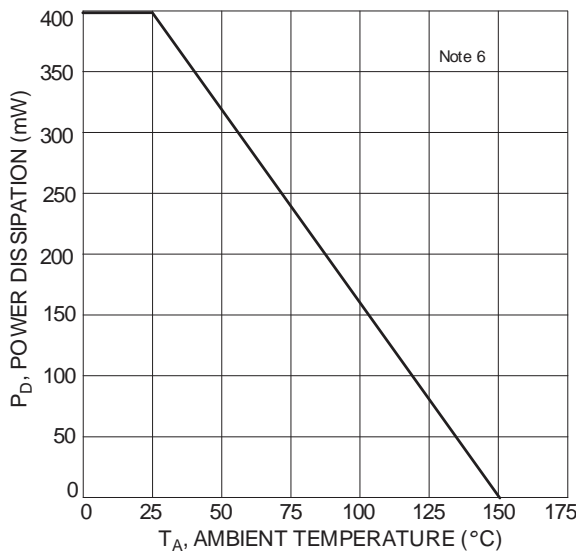


Fig. 1 Power Derating Curve

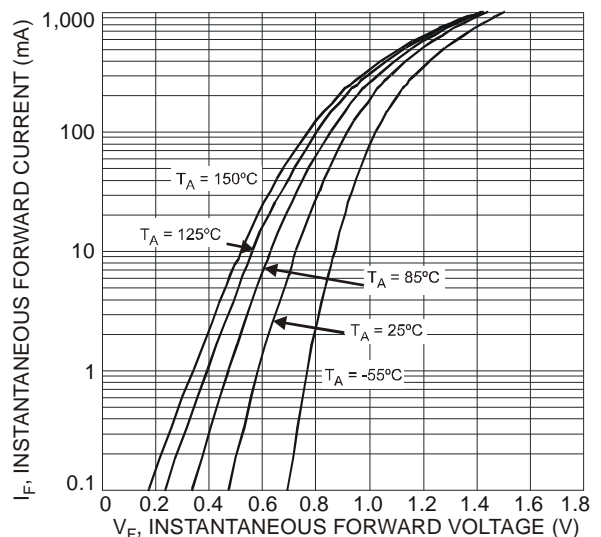


Fig. 2 Typical Forward Characteristics

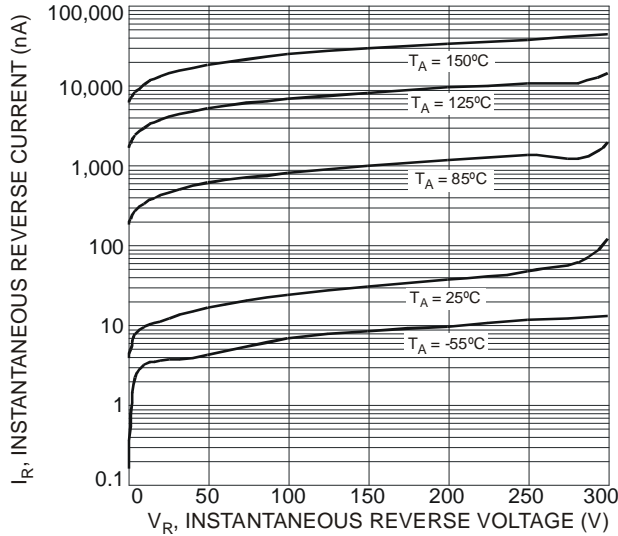


Fig. 3 Typical Reverse Characteristics

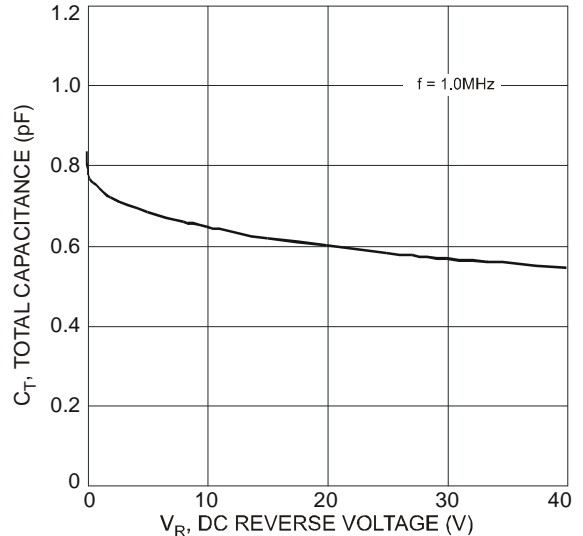
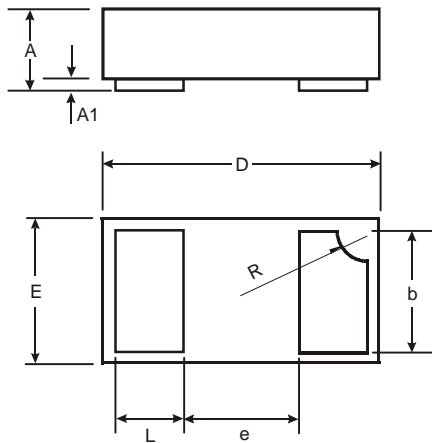


Fig. 4 Total Capacitance vs. Reverse Voltage

### Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

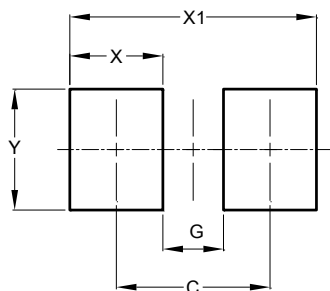


X1-DFN1006-2			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0	0.05	0.03
b	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	-	-	0.40
L	0.20	0.30	0.25
R	0.05	0.15	0.10

All Dimensions in mm

### Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



Dimensions	Value (in mm)
C	0.70
G	0.30
X	0.40
X1	1.10
Y	0.70

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